

# 1002MP

2 Watts, 35 Volts

Pulsed Avionics at 960-1215 MHz

## GENERAL DESCRIPTION

The 1002MP is a COMMON BASE transistor capable of providing 2 Watts of pulsed RF output power in the band 960 to 1215 MHz. This transistor is specifically designed for pulsed Avionics amplifier applications. It utilizes gold metallization and low thermal resistance packaging to provide high reliability and supreme ruggedness.

## ABSOLUTE MAXIMUM RATINGS

### Maximum Power Dissipation

Device Dissipation @ 25°C 7 W

### Maximum Voltage and Current

Collector to Base Voltage ( $BV_{ces}$ ) 50 V

Emitter to Base Voltage ( $BV_{ebo}$ ) 3.5 V

Collector Current ( $I_c$ ) 250 mA

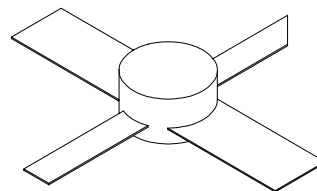
### Maximum Temperatures

Storage Temperature -40 to +150 °C

Operating Junction Temperature +200 °C

## CASE OUTLINE

55FW-1



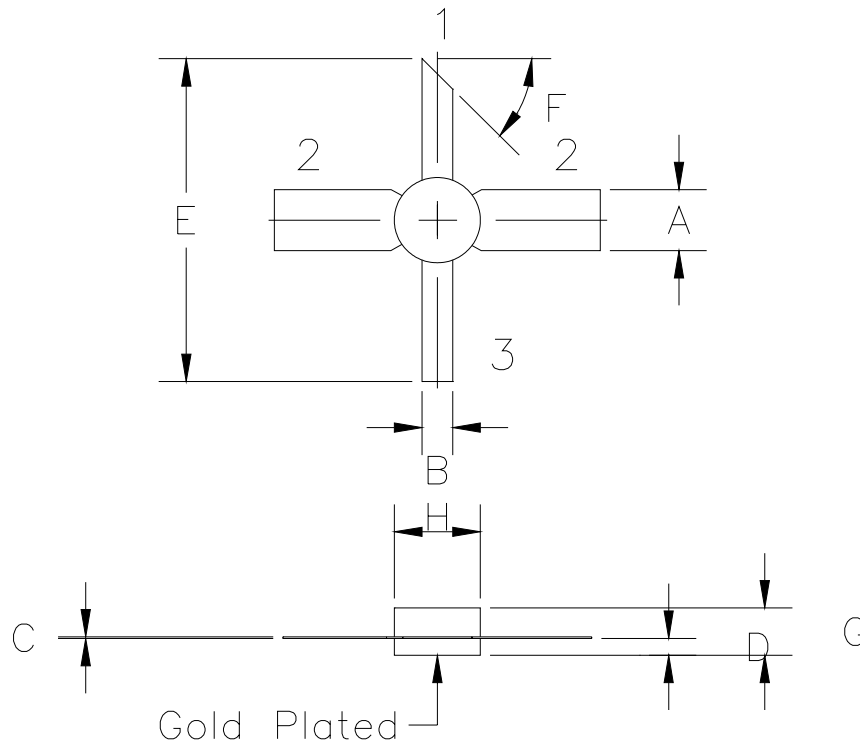
## ELECTRICAL CHARACTERISTICS @ 25°C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$P_{out}$	Power Output	F = 1150 MHz  V <sub>cc</sub> = 35 Volts Pulse width = 20 μs LTDF = 1%	2.0	2.5		W
$P_{in}$	Power Input				0.3	W
$P_g$	Power Gain		10	11		dB
$\eta_c$	Collector Efficiency			45		%
VSWR	Load Mismatch Tolerance				10:1	

## FUNCTIONAL CHARACTERISTICS @ 25°C

$BV_{ebo}$	Emitter to Base Breakdown	I <sub>e</sub> = 50 mA	3.5			V
$BV_{ces}$	Collector to Emitter Breakdown	I <sub>c</sub> = 100 mA	50			V
$h_{FE}$	DC – Current Gain	V <sub>ce</sub> = 5V, I <sub>c</sub> = 100 mA	20			
C <sub>ob</sub>	Capacitance			2.5	5.0	pF
$\theta_{jc}^1$	Thermal Resistance				25	°C/W

**1002MP**



STYLE 1:  
 PIN1 = COLLECTOR  
 2 = BASE (2X)  
 3 = EMITTER

STYLE 2:  
 PIN1 = COLLECTOR  
 2 = EMITTER (2X)  
 3 = BASE

DIM	MILLIMETER	±TOL	INCHES	±TOL
A	5.08	.13	.200	.005
B	7.11 DIA	.13	.280 DIA	.005
C	0.13	.02	.005	.001
D	1.40	.13	.055	.005
E	26.92	.64	1.060	.025
F	45°	5°	45°	5°
G	3.94	REF	.155	REF
H	2.54	.13	.100	.005

